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May 2009

FDMS8670

N-Channel Power Trench® MOSFET 30V, 42A, 2.6m Ω

Features

- Max $r_{DS(on)}$ = 2.6m Ω at V_{GS} = 10V, I_D = 24A
- Max $r_{DS(on)}$ = 3.8m Ω at V_{GS} = 4.5V, I_D = 18A
- 100% UIL Tested
- RoHS Compliant

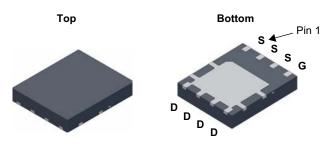


General Description

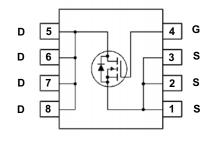
This N-Channel MOSFET is produced using Fairchild Semiconductor's latest proprietary Power Trench® process that has been especially tailored to minimize on-resistance. This part exhibits industry leading switching FOM (RDS*Qgd) to enhance DC-DC synchronous rectifier efficiency.

Application

■ DC - DC Conversion



Power 56



MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			30	V
V _{GS}	Gate to Source Voltage			±20	V
	Drain Current -Continuous (Package limited)	T _C = 25°C		42	
	-Continuous (Silicon limited)	T _C = 25°C		135	
ID	-Continuous	T _A = 25°C	(Note 1a)	24	_ A
	-Pulsed			150	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	288	mJ
D	Power Dissipation	T _C = 25°C		78	w
P_{D}	Power Dissipation	T _A = 25°C	(Note 1a)	2.5	vv
T _J , T _{STG}	Operating and Storage Junction Temperature R	ange		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case		1.6	°C/W
R _{e,IA}	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS8670	FDMS8670	Power 56	13"	12 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Parameter Test Conditions		Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I _D = 250μA, referenced to 25°C		19.5		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} = 0V, V _{DS} = 24V,			1	μА
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V, V _{DS} = 0V			±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.0	1.7	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250μA, referenced to 25°C		-5.9		mV/°C
		V _{GS} = 10V, I _D = 24A		2.1	2.6	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 18A$		3.0	3.8	mΩ
		$V_{GS} = 10V$, $I_D = 24A$, $T_J = 125$ °C		3.0	3.8	
9 _{FS}	Forward Transconductance	$V_{DD} = 5V, I_{D} = 24A$		117		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 45V V - 0V		2965	3940	pF
C _{oss}	Output Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		1395	1855	pF
C _{rss}	Reverse Transfer Capacitance			180	265	pF
R_g	Gate Resistance	f = 1MHz		1.3		Ω

Switching Characteristics

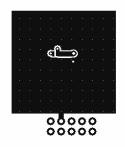
t _{d(on)}	Turn-On Delay Time				14	24	ns
t _r	Rise Time		V_{DD} = 15V, I_{D} = 24A, V_{GS} = 10V, R_{GEN} = 6Ω		5	10	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, R _{GEN}			33	53	ns
t _f	Fall Time				4	10	ns
Q_g	Total Gate Charge	V _{GS} = 0V to 10V			45	63	nC
Qg	Total Gate Charge	V _{GS} = 0V to 5V	V _{DD} = 15V,		23	33	nC
Q _{gs}	Gate to Source Charge		I _D = 24A		8.3		nC
Q_{gd}	Gate to Drain "Miller" Charge				5.7		nC

Drain-Source Diode Characteristics

V _{SD} Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_S = 24A$ (Note 2)		8.0	1.3	\/	
V _{SD}	Source to Drain Diode Forward voltage	$V_{GS} = 0V, I_S = 2.1A$ (Note 2)		0.7	1.2	V
t _{rr}	Reverse Recovery Time	I _F = 24A, di/dt = 100A/μs		44	71	ns
Q _{rr}	Reverse Recovery Charge			27	43	nC

NOTES

^{1.} R_{0,1A} is determined with the device mounted on a 1in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,1C} is guaranteed by design while R_{0,CA} is determined by the user's board design.



a. 50° C/W when mounted on a 1 in^2 pad of 2 oz copper.



b. 125°C/W when mounted on a minimum pad of 2 oz copper.

^{2.} Pulse Test: Pulse Width < 300μ s, Duty cycle < 2.0%.

^{3.} Starting T_J = 25°C, L = 1mH, I_{AS} = 24A, V_{DD} = 27V, V_{GS} = 10V.

Typical Characteristics T_J = 25°C unless otherwise noted

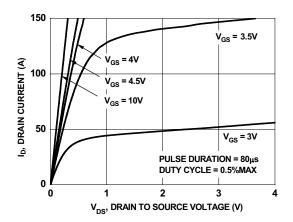


Figure 1. On-Region Characteristics

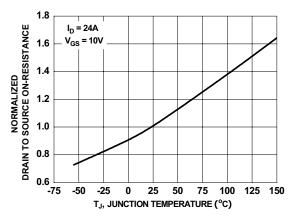


Figure 3. Normalized On-Resistance vs Junction Temperature

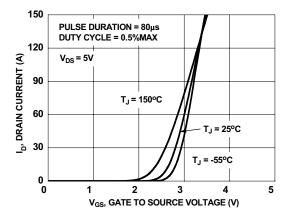


Figure 5. Transfer Characteristics

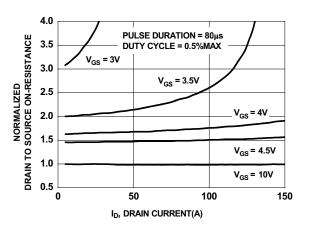


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

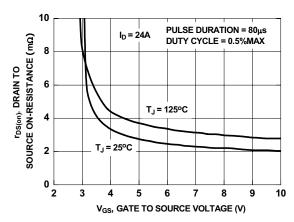


Figure 4. On-Resistance vs Gate to Source Voltage

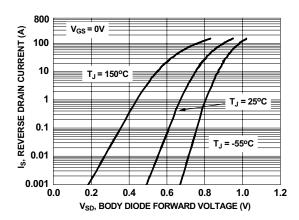


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

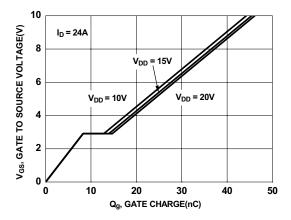


Figure 7. Gate Charge Characteristics

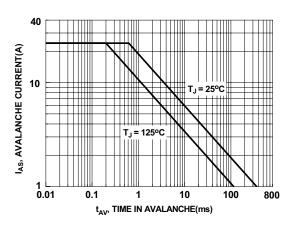


Figure 9. Unclamped Inductive Switching Capability

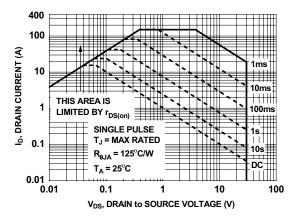


Figure 11. Forward Bias Safe Operating Area

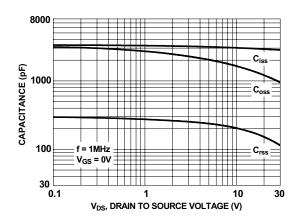


Figure 8. Capacitance vs Drain to Source Voltage

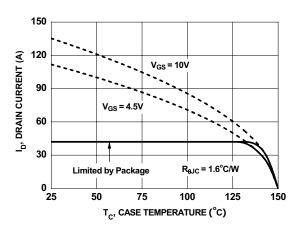


Figure 10. Maximum Continuous Drain Current vs Case Temperature

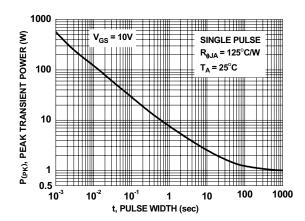


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics T_J = 25°C unless otherwise noted

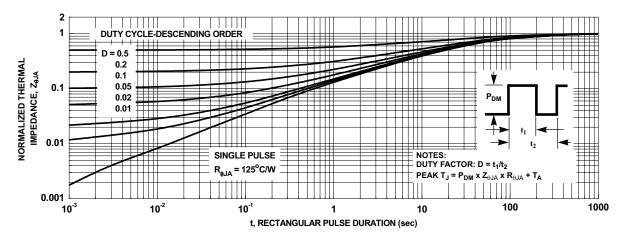
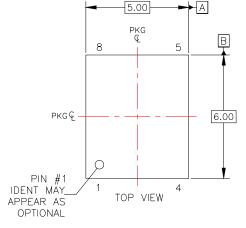
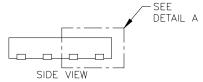
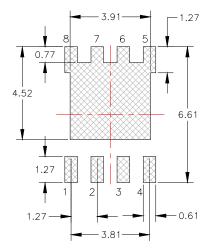


Figure 13. Transient Thermal Response Curve

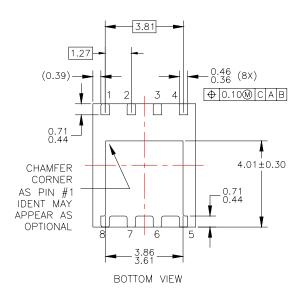
Dimensional Outline and Pad Layout

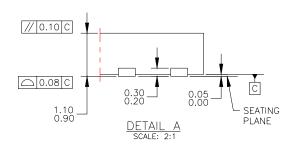


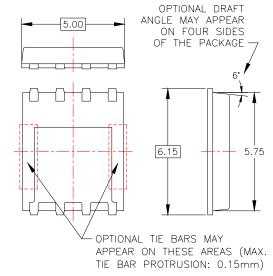




LAND PATTERN RECOMMENDATION







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- DATED OCTOBER 2002.

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